TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74VHCT74AF, TC74VHCT74AFN, TC74VHCT74AFT

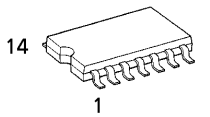
DUAL D - TYPE FLIP - FLOP WITH PRESET AND CLEAR

(Note) The JEDEC SOP (FN) is not available in Japan.

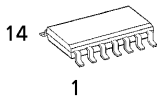
The TC74VHCT74 is an advanced high speed CMOS D - FLIP FLOP fabricated with silicon gate C^{2}MOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.
The signal level applied to the D INPUT is transferred to Q OUTPUT during the positive going transition of the CK pulse.
$\overline{CLR}$ and $\overline{PR}$ are independent of the CK and are accomplished by setting the appropriate input low.
The input voltage are compatible with TTL output voltage.
This device may be used as a level converter for interfacing 3.3V to 5V system.
Input protection and output circuit ensure that 0 to 5.5V can be applied to the input and output*1 pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input / output voltages such as battery back up, hot board insertion, etc.
*1 : V_{CC} = 0V

FEATURES :

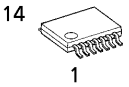
- High Speed ····· f_{MAX} = 160MHz(typ.) at V_{CC} = 5V
- Low Power Dissipation····· I_{CC} = 2μA(Max.) at Ta = 25°C
- Compatible with TTL outputs ··· V_{IL} = 0.8V (Max.), V_{IH} = 2.0V (Min.)
- Power Down Protection is provided on all inputs and outputs
- Balanced Propagation Delays····· $t_{pLH} \simeq t_{pHL}$
- Pin and Function Compatible with the 74 series (74AC / HC / F / ALS / LS etc.) 74 type.



F (SOP14-P-300-1.27)
Weight : 0.18g (Typ.)

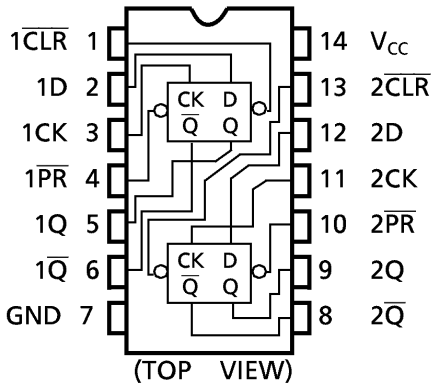


FN (SOL14-P-150-1.27)
Weight : 0.12g (Typ.)



FT (TSSOP14-P-0044-0.65)
Weight : 0.06g (Typ.)

PIN ASSIGNMENT

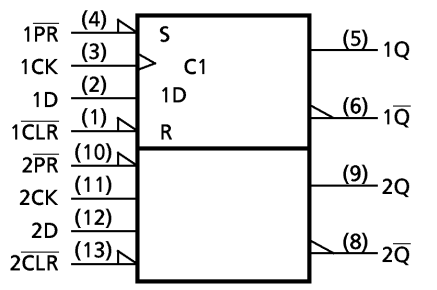


TRUTH TABLE

INPUTS				OUTPUTS		FUNCTION
$\overline{CLR}$	$\overline{PR}$	D	CK	Q	$\overline{Q}$	
L	H	X	X	L	H	CLEAR
H	L	X	X	H	L	PRESET
L	L	X	X	H	H	—
H	H	L	↑	L	H	—
H	H	H	↑	H	L	—
H	H	X	↓	Q_n	$\overline{Q}_n$	NO CHANGE

X : Don't Care

IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	−0.5~7.0	V
DC Input Voltage	V_{IN}	−0.5~7.0	V
DC Output Voltage	V_{OUT}	−0.5~7.0 (Note 1)	V
		−0.5~V_{CC} + 0.5 (Note 2)	
Input Diode Current	I_{IK}	−20	mA
Output Diode Current	I_{OK}	±20 (Note 3)	mA
DC Output Current	I_{OUT}	±25	mA
DC V_{CC}/Ground Current	I_{CC}	±50	mA
Power Dissipation	P_D	180	mW
Storage Temperature	T_{stg}	−65~150	°C

(Note 1) V_{CC} = 0V
(Note 2) High or Low State. I_{OUT} absolute maximum rating must be observed.
(Note 3) V_{OUT} < GND, V_{OUT} > V_{CC}

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	4.5~5.5	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~5.5 (Note 4)	V
		0~V_{CC} (Note 5)	
Operating Temperature	T_{opr}	−40~85	°C
Input Rise and Fall Time	dt / dV	0~20	ns / V

(Note 4) V_{CC} = 0V
(Note 5) High or Low State.

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	CONDITON		V_{CC} (V)	Ta = 25°C			Ta = −40~85°C		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V_{IH}			4.5~5.5	2.0	—	—	2.0	—	V
Low - Level Input Voltage	V_{IL}			4.5~5.5	—	—	0.8	—	0.8	V
High - Level Output Voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50μA	4.5	4.40	4.50	—	4.40	—	V
			I_{OH} = −8mA	4.5	3.94	—	—	3.80	—	
Low - Level Output Voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50μA	4.5	—	0.0	0.1	—	0.1	V
			I_{OL} = 8mA	4.5	—	—	0.36	—	0.44	
Input Leakage Current	I_{IN}	V_{IN} = 5.5V or GND		0~5.5	—	—	±0.1	—	±1.0	μA
Quiescent Supply Current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	2.0	—	20.0	μA
	I_{CCT}	PER INPUT : V_{IN} = 3.4V OTHER INPUT : V_{CC} or GND		5.5	—	—	1.35	—	1.50	mA
Output Leakage Current	I_{OPD}	V_{OUT} = 5.5V		0	—	—	0.5	—	5.0	μA

TIMING REQUIREMENTS (Input $t_r = t_f = 3ns$)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C	Ta = −40~85°C	UNIT
			V_{CC} (V)	LIMIT	LIMIT	
Minimum Pulse Width (CK)	$t_{W(L)}$ $t_{W(H)}$		5.0 ± 0.5	5.0	5.0	ns
Minimum Pulse Width ($\overline{CLR}$, $\overline{PR}$)	$t_{W(L)}$		5.0 ± 0.5	5.0	5.0	
Minimum Set - up Time	t_s		5.0 ± 0.5	5.0	5.0	
Minimum Hold Time	t_h		5.0 ± 0.5	0.0	0.0	
Minimum Removal Time ($\overline{CLR}$, $\overline{PR}$)	t_{rem}		5.0 ± 0.5	3.5	3.5	

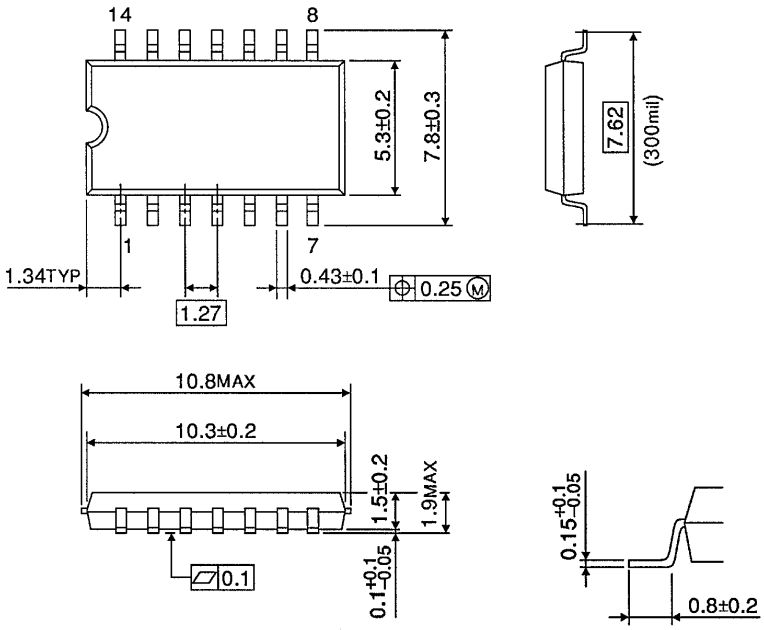
AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3ns$)

PARAMETER	SYMBOL	TEST CONDITION			Ta = 25°C			Ta = −40~85°C		UNIT
			V_{CC} (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (CK - Q , $\overline{Q}$)	t_{pLH} t_{pHL}		5.0 ± 0.5	15	—	5.8	7.8	1.0	9.0	ns
				50	—	6.3	8.8	1.0	10.0	
Propagation Delay Time ($\overline{CLR}$, $\overline{PR}$ - Q , $\overline{Q}$)	t_{pLH} t_{pHL}		5.0 ± 0.5	15	—	7.6	10.4	1.0	12.0	
				50	—	8.1	11.4	1.0	13.0	
Maximum Clock Frequency	f_{MAX}		5.0 ± 0.5	15	100	160	—	80	—	MHz
				50	80	140	—	65	—	
Input Capacitance	C_{IN}				—	4	10	—	10	pF
Power Dissipation Capacitance	C_{PD}	(Note 6)			—	24	—	—	—	

Note (6) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation :

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 2 \text{ (per F / F)}$$

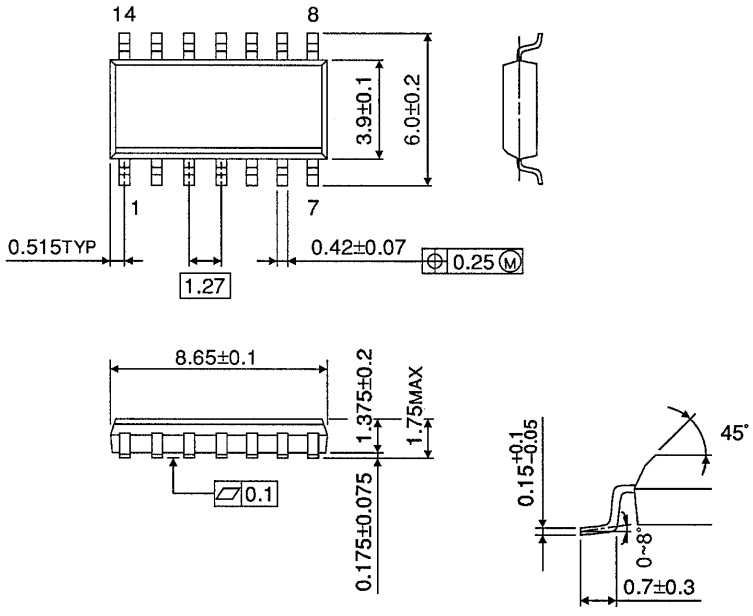
SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27) Unit in mm



Weight : 0.18g (Typ.)

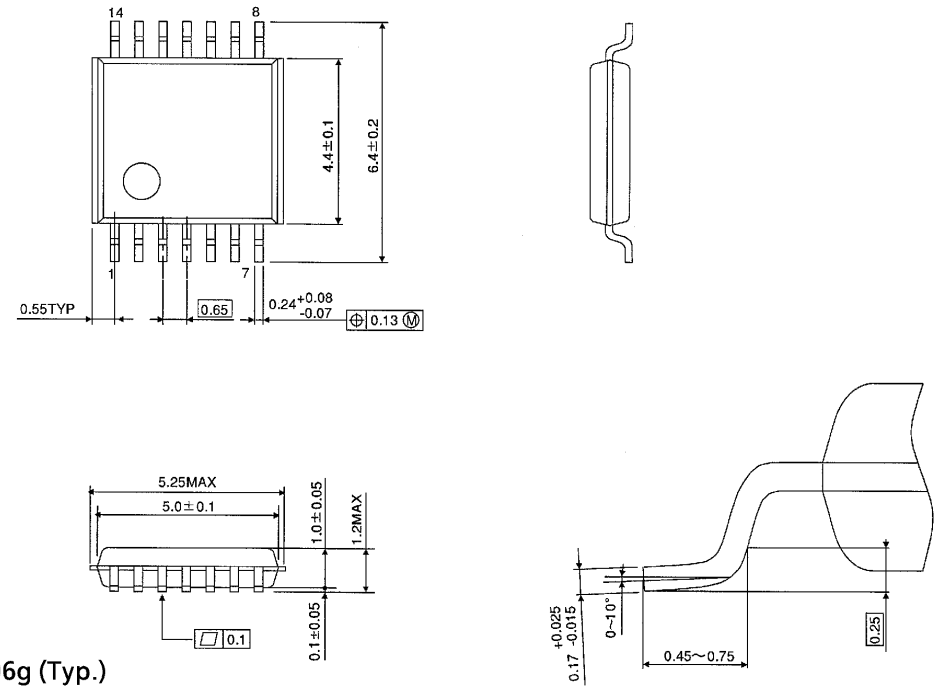
SOP 14PIN (150mil BODY) PACKAGE DIMENSIONS (SOL14-P-150-1.27) Unit in mm

(Note) This package is not available in Japan.



Weight : 0.12g (Typ.)

TSSOP 14PIN PACKAGE DIMENSIONS (TSSOP14-P-0044-0.65) Unit in mm



Weight : 0.06g (Typ.)

RESTRICTIONS ON PRODUCT USE

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.